An Optimized Self-Adaptive Thermal Radiation Turn-Down Coating with Vanadium Dioxide Nanowire Array

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ABSTRACT: High performance metasurfaces for thermal radiative cooling applications can be identified using computational optimization methods. This work has identified an easy-to-fabricate temperature phase transition VO2 nanowire array laid atop dielectric BaF2 Fabry-Perot cavity-onmetal with total coating thickness of $2 \mu m$. This optimized structure has ability to self-adaptively switch between high reflectance at low temperature to high emissivity at high temperature in the broad thermal infrared spectrum. This design demonstrates exceptional turn-down figure-of-merit compared to previously realized configurations utilizing VO2 metasurfaces and multilayers. The mechanism is achieved with a sub-wavelength nanowire array effective medium that switches between anti-reflecting gradient coating and Fabry-Perot interference. This thin metasurface coating could impact self-cooling of the solar cells, batteries, and electrical devices where risk presents at high temperatures.

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1 **1. INTRODUCTION**

2 Optical properties of thin films can be manipulated by introducing multilayered nano-patterns 3 or periodic nanoelements that interface with electromagnetic waves from the visible to infrared. 4 Various flavors of engineered nanoscale coatings include sub-diffraction plasmonic gratings [1- 5 3], ultra-high reflection high contrast gratings [4-6], traditional diffraction gratings [7], and simple 6 multilayers such as Fabry-Perot quarter-wave layers [8-10]. Among the considered, these 7 nanoscale metasurfaces are potentially useful in photovoltaic device improvement and thermal 8 emission regulation [11-14]. Yet the key attribute to be sought after is thermochromic tuning – the 9 ability to change optical properties with engineered surface temperature – which may result in self-10 cooling amid temperature or environmental changes. Temperature phase change materials, such 11 as vanadium dioxide (VO_2) [9, 15, 16], SmNiO₃ [17, 18], Ti₃O₅ [19], and many others can tailor 12 the optical properties when things get heated.

13 VO2 integrated in photonic multilayers and gratings have demonstrated thermal radiative 14 switching [9, 15, 20] A common coating design utilizes the concept of Fabry-Perot cavity 15 interference to obtain low emittance when cool and high emittance at hot [9]. More complex 16 multilayers can be added, for the purpose of daytime radiative cooling, as absorption to solar 17 radiation is minimized compared to the emission in the infrared [15]. Other designs have patterned 18 at-wavelength size scale cylindrical gratings [21, 22]. So far, the turn-down thermal performance 19 of such coatings has been less than anticipated. The optimal thermochromic metastructure needs 20 to be designed by weighting the Planck blackbody distribution at the corresponding wavelengths 21 and temperatures close to the phase transition, as determined by Wien's displacement law. This 22 work also considers the optimized structure that is easily feasible for nano/micro-fabrication, for 23 a future in large scale-produced flexible radiative cooling blankets.

24 This work proposes a high turn-down grating by computational optimization of $\rm VO_2$ nanowires 25 in a thin film. VO2 has a phase transition temperature at 340 K [14, 23, 24], where the phonon-26 electron structure transforms from insulating to metallic at temperatures above this transition 27 temperature [25]. By randomized trials of at-and sub-wavelength deposited VO2 nano/micro-28 features, a periodic VO2 nanowire array and a solid VO2 monolayer that sandwiches a quarter-29 wave thick lossless dielectric. Fabricated VO2 nanowires typically of 50-150 nm in diameter were 30 recently used demonstrating the breakdown on the Franz-Wiedemann law in thermoelectricity

31 [25]. These VO2 nanowires were fabricated through vapor transport method, a bottom-up method 32 [25-28], and these VO2 nanobeams can be laid and aligned in-plane, compared to the top-down 33 photolithography and etching processes for traditional at-wavelength gratings [24]. This bottom-34 up method can greatly reduce complexity in fabrication, where minimal coating thickness is 35 needed.

36 We utilize a Monte-Carlo optimization method to obtain the best nanowire array period and 37 width of square cross-section VO₂ nanowires [29]. This method is applied to obtain the VO₂ 38 monolayer as well, which serves as a gradual index anti-reflection layer above the fully-reflecting 39 silver substrate. The broadband reflectance or broadband emissivity turn-down performance is 40 quantified with a turn-down performance figure-of-merit (FOM), and compared with other $VO₂$ 41 phase transition passive thermal radiation self-cooling coatings. The proposed structure has a total 42 thickness of about 2.5 µm, including the 500 nm silver substrate. In this design, the coating on a 43 flexible polymer backing sheet can be applied to alleviate the loss in efficiency for solar cells, 44 whose temperatures can be as high as 80° C in summers under highly irradiative climates, such as 45 Texas. The flexible coating can be applied to one or both sides of a vacuum gap between a solar 46 cell housing and the roof. Similarly, it can be utilized for cooling compact processor components 47 that gets as warm as 80 to 100°C. Other usages include thermal management for lithium-ion cells 48 casings, passive-switched spacecraft insulation blankets, and other common Earth-temperature 49 thermal regulation applications.

50 **2. COMPUTATIONAL METHODS**

51 *2.1. Theory of Optical Coatings*

52 In this paper, Rigorous Coupled-Wave Analysis (RCWA), a well-established multilayered 53 diffraction method to solve Maxwell equations [30, 31], is utilized to calculate the optical radiative 54 properties of the optimized periodic coatings. The materials and geometrical parameters of the 55 proposed coating is shown in Figure 1: The grating has a period of Λ, nanowire width of *w*, 56 nanowire height of *h*, distance between nanowires *b*, thickness of the lossless dielectric is *d*D, and 57 thickness of the VO₂ sub-monolayer is d_{VQ_2} . Initially, the nanowire aspect ratio can be non-square 58 to demonstrate possible effects.

59 In designing toward desirable high reflection or high emission properties, selection of optical 60 parameters is important in tailoring its optical parameters. The contrast of the dielectric layers 61 helps construct an anti-reflecting coating, where each transparent layer satisfies the geometric 62 mean of the surround layers, such that $n_1 = \sqrt{n_0 n_2}$ [32]. The underlying totally reflecting metal 63 substrate can vary among aluminum, silver, gold, and others that are opaque and reasonably 64 produced at sub-micron thickness. The anti-reflecting layer thicknesses must also satisfy quarter-65 wave law, such that $h = \lambda/4n$. This quarter-wave method is widely used to determine broadband 66 reflectance at certain wavelength range known as Bragg reflector, where high- and low- refractive 67 index materials are stacked into multilayers with quarter-wave thickness [33]. On the other hand, 68 Fabry-Perot resonance are formed by constructive interference of electromagnetic waves within 69 the dielectric spacer sandwiched by metallic thin films. Ideally, these metallic boundaries are 70 infinitesimally-thin and lossless. This produces perfect absorptivity or emissivity, and perfect 71 transmissivity at moded frequencies [8, 9]. The switching between one to the other mechanism is 72 how our turn-down capability is designed. In addition, for periodic features at the sub-wavelength, 73 such that $\Lambda \ll \lambda$, effective medium theory (EMT) can be applied to approximate the optical 74 properties of gratings as expressed by a single layer composed of a filling ratio of dielectric 75 functions [31, 34].

76 *2.2. Radiative Properties*

77 The dielectric function of \rm{VO}_2 are obtained from empirical spectroscopy of its thin films [35]. 78 Its optical properties are expressed with effective medium and Fermi-Dirac like distribution as 79 shown,

80
$$
\varepsilon_{\text{eff}}^{0.3} = (1 - f) \varepsilon_{\text{i}}^{0.3} + f \varepsilon_{\text{m}}^{0.3} \tag{1}
$$

$$
f(T) = \frac{1}{1 + \exp\left[\frac{W}{k_{\mathrm{B}}}\left(\frac{1}{T} - \frac{1}{T_{\mathrm{h}}}\right)\right]}
$$
(2)

82 where ε_i and ε_m is the dielectric function for insulator and metal VO₂ respectively. *W*=3.37 K is 83 width of the temperature range of metal-insulator transition. The partial monoclinic-to-rutile lattice 84 phase transition occurs at $T_h = 78.5$ °C, where at this temperature, 50% of VO₂ is metallic [35]. 85 Thus, the onset transition temperature of $VO₂$ from insulator to metal is 68 $°C$. In Fig. 2 (a), the 86 imaginary part of the refractive index in $VO₂$ for the cold state is close to zero in the mid- to far87 infrared (around 4 to 10 μ m). This infrared transparent region is highlighted in gray, and can play 88 an important role in low absorption. On the other hand, it is absorbing in visible and far-infrared 89 region.

90 As shown in Fig. 2(b), there are a few broadly infrared-transparent dielectric candidate 91 materials that can be utilized as the dielectric spacer. These include barium fluoride (BaF2), zinc 92 sulfide (ZnS), and silicon (Si). The most common, silicon, has broadly constant refractive index 93 of around $n = 3.4$, with no extinction coefficient provided undoped low number density and optical 94 quality [31]. For BaF2 and ZnS, the refractive index is lower, but have absorption component in 95 far infrared region, due to the Reststrahlen effect of gaps in the upper-level electron bands [36, 37] 96 The lower refractive index is appreciated in the arrangement of anti-reflection gradient index of 97 layers. In certain other turn-down coating designs, $MgF₂$ can also be the candidate for the dielectric 98 materials. However, it has a significant absorption near the Reststrahlen band, which may result in 99 reduction in the performance of radiative properties [38]. Insulators with absorption in infrared 100 wavelengths up to 30 µm must be avoided, as a wavelength window cutoff in the upper limit leaves 101 more than 10% of Planck radiation at atmospheric temperatures unaccounted for. The balance of 102 broad infrared transparency and close to unity refractive index needs to be considered.

103 *2.3. Optimization of Parameters*

104 The parameter optimization scheme is conducted by creating four arrays of random *N* 105 numbers, r_i , for randomizing Λ, *b*, *h*, and d νο₂. The arrays consisting of random numbers are then 106 used to produce random value of size arrays for those four parameters as: $\Lambda = \Lambda_0 \pm r_1 \Lambda_0$, $\mathbf{b} = b_0 \pm r_1 \Lambda_0$ *r*₂*b*₀, *h* = *h*₀ ± *r*₃*h*₀, and *d*_{VO₂} = *d*₀ ± *r*₄*d*₀. Candidates with *b* > Λ are rejected. The *N* combinations 108 of candidates are created and evaluated with the following figure-of-merit (FOM),

109
$$
\text{FOM} = \frac{R300}{R350} = \frac{\int_{0.3\mu\text{m}}^{30\mu\text{m}} \rho_{\lambda,300} E_{\text{BB},300} d\lambda}{\int_{0.3\mu\text{m}}^{30\mu\text{m}} \rho_{\lambda,350} E_{\text{BB},350} d\lambda}
$$
(3)

110 where ρ_{λ} is the spectral reflectivity, and $E_{BB,T}$ is the spectral emissive power which expressed as $E_{\text{BB},T} = \pi I_{\text{BB},T}$, where $I_{\text{BB},T} = (4\pi^2 c_0^2 \hbar / \lambda^5) / [\exp(2\pi \hbar c_0 / \lambda k_B T) - 1]$ is the blackbody intensity at 112 the corresponding temperature *T*. The integrated wavelength ranges from 0.3 μ m and 30 μ m, which 113 covers adequate sampling of the blackbody spectrum at atmospheric temperatures up to the Solar 114 spectrum. The FOM is based on coating reflectivity to normalize from the opaque metal substrate, 115 for sake of FOM comparison with other configurations on other metal substrates. The reflectivity 116 is used to assess the coating's ability to reject surrounding radiation at higher temperature. On the 117 other hand, for other calculations, the spectral emissivity is calculated as $\varepsilon_{\lambda} = 1 - \rho_{\lambda}$, considering 118 that Kirchhoff's law of radiation is satisfied being the substrate is thick enough to be opaque. By 119 fitting the parameter inputs into this summative FOM metric, further parametric stipulations can 120 be applied to the next round of optimizations as explained in next section. Since the optimization 121 consists of four parameters to randomize, $N = 10^4$ candidates are sufficient to search for the optimal 122 structure. Yet optimizing more parameters could require additional samples needed, but recent 123 machine learning techniques such as Bayesian optimization may be implemented in the future for 124 its adaptive learning of the best parameters with reasonable convergence [39].

125 **3. RESULTS AND DISCUSSION**

126 *3.1. Radiative Turn-Down Performance of Optimized Coating*

127 In this work, BaF_2 is chosen as the dielectric spacer and d_{BaF_2} is quarter-wave thickness set 128 constant as $λ_0$ / $4n_{\text{BaF}_2} = 1.385$ μm. The center wavelength $λ_0$ is chosen as 8.2 μm, corresponding 129 to emissive power at 80° C (hot condition). The cold condition is selected to be 30° C, a typical 130 warm day or summer night in Texas. BaF₂ has a low index of approximately $n_{\text{BaF}_2} = 1.5$, which 131 contrasts highly against VO2. BaF2 is preliminarily selected as the lossless dielectric due to its 132 broad essentially zero imaginary component of the refractive index up to the Reststrahlen 133 absorption peak near 50 μ m [36]. The dielectric function of Ag is Drude-like with plasma constants 134 from Ref. [1], and that of BaF₂ is obtained from Ref. [37].

135 First, the d_{VO_2} sub-monolayer is found to have optimal thickness at 450 nm via our 136 randomization trials. It is thinner than the anticipated quarter-wave thickness of λ_0 / $4n\text{vo}_2 = 840$ 137 nm, where $n_{\text{VO}_2} = 2.38$ at $\lambda = 8.2$ µm. The maximized FOM is quite broad over $N = 10^4$ samples, 138 with no random scattering of outliers. Deviations of a few tens of nanometers from this value 139 remains high performance. On searching for an optimal filling ratio of VO₂ nanowire-to-period (ϕ $140 = w / \Lambda$, we narrowed it to the range between 0.4 to 0.6. Thus, a reasonable additional restriction 141 can be applied to the optimization method where the width of the VO₂ nanowire cross-section is 142 equal to the nanowire height. Optimizations of rectangular nanowires did not result in additional

143 maximization of FOM. Square cross-section VO2 nanowires with high length-to-width aspect 144 ratios have been realized for nanoscale applications [23]. This round of optimizations is conducted 145 with the aspect ratio restrictions, resulting in the best optimized structure with parameters: Λ = 146 194 nm, $b = 114$ nm, $w = h = 80$ nm, $d_{\text{BaF}_2} = 1.385$ µm, and $d_{\text{VO}_2} = 0.450$ µm. This design 147 corresponds to the highest FOM = 1.47, meaning that the emitted thermal radiation at high 148 temperature exceeds that absorbed at low temperature.

149 The thermal radiation turn-down mechanism can be explained starting with Fig. 2(a), where 150 the large difference of extinction coefficient κ between 30°C and 80°C is observed in the 151 highlighted gray region of the spectrum. This component is close to zero at the low temperature, 152 but well above one and increasing in magnitude in the mid to far infrared region at the high 153 temperature. Figure 3(a) shows the averaged spectral emissivity between TM- and TE-polarized 154 waves calculated by RCWA. The emissivity is unavoidably high at any temperature in the visible 155 wavelengths, as there is always a bandgap transition. Meanwhile in the infrared region, the region 156 corresponding to the extinction coefficient flip overlaps with the atmospheric transparency 157 window (inverse of clouds on a warm day near 290 K). With the optimized design, the emissivity 158 switches between low emissivity and high emissivity as the temperature increases. Additionally, 159 the hemispherical emissivity (ε^h) across all polar incident angles and averaged electromagnetic 160 wave polarizations shows small differences compared to the normal emissivity, except for the far-161 infrared region beyond 25 μ m. This is attributed to some minor absorption due to the off-quarter-162 wave thickness attenuation length from a slightly lossy $BaF₂$ as it approaches its Reststrahlen band, 163 and will be dissected in our forthcoming discussion.

164 The normal polar incident angle emissivity in transverse magnetic (TM) and transverse electric 165 (TE) wave calculated in effective medium theory (EMT) are shown in Fig. 3(b), and it shows 166 drastic differences between them. This is due to differences in effective refractive index in 167 extraordinary and ordinary components, as expressed by [34],

168
$$
\varepsilon_{\text{TM}} = \frac{\varepsilon_{\text{VO}_2} \varepsilon_{\text{air}}}{(1 - \phi) \varepsilon_{\text{VO}_2} + \phi \varepsilon_{\text{air}}} \tag{4}
$$

$$
\varepsilon_{\text{TE}} = \phi \varepsilon_{\text{VO}_2} + (1 - \phi) \varepsilon_{\text{air}} \tag{5}
$$

170 where ϕ is the width-to-period filling ratio for gratings. The index of air is $\varepsilon_{\text{air}} = 1.0$. The resulting 171 effective refractive index for TM wave is calculated at around $n_{TM} \sim 1.3$, and has low κ_{TM} value for 172 both 30 \degree C and 80 \degree C, which suppresses the emissivity. On the other hand, the contribution of VO₂ 173 is much higher in the effective refractive index for TE waves, which $n_{\text{TE}} \sim 1.7$ and \sim 3.6 at 30°C 174 and 80°C, respectively. The *κ*_{TE} value is much higher at 80°C, given by 2.0 to 4.0, and so higher 175 emissivity is obtained. We note the near-perfect emissivity of 0.997 at 10.5 m, attributed to the 176 optimized design of the Fabry-Perot mechanism.

177 The following figures further investigate the underlying mechanisms of the turn-down 178 coating's near-idealized performance. Figure 4 shows the emissivity calculated by RCWA as a 179 function of both incident angle and wavelength. The results show the high turn-down performance 180 of emissivity between cold and hot cases for both TM and TE waves. This is especially true in the 181 neighborhood of 10 μ m, as the normal and broadly oblique emissivity switches from near-zero to 182 near-unity. The emissivity in the TM wave is slightly suppressed to due to the extinction coefficient 183 in the effective medium extraordinary polarization being close to zero for higher temperature. On 184 the other hand, the contrast in TE wave polarization is higher due to the switch between insulating 185 and metallic dispersion along the nanowire. In essence, the axial dispersion along the nanowire 186 offers the highest contrast corresponding to the TE polarization, while maintaining good 187 transmittance overall due to the sparsity of interactions of electric fields along the nanowire cross-188 section. Interestingly, the high emissivity observed at far-infrared region for TM wave is not 189 present at TE wave. EMT was also able to capture the angular polarization dependency in TM 190 wave, where the emissive power is produced only in *x-z* plane at normal polar incident angle.

191 Figure 5 demonstrates the power dissipation density (PDD) plots between cold and hot states. 192 PDD in W/m^3 is given by,

193
$$
\text{PDD} = \frac{1}{2} \varepsilon_0 \text{Im}(\varepsilon) \omega |\mathbf{E}|^2 \tag{6}
$$

194 where ω is the angular frequency corresponding to the wavelength, and \boldsymbol{E} is the local electric field 195 as function of the *x-z* plane. In Fig. 5 (a), the mechanism behind the high reflectance in the cold 196 state is due to graded refractive index from top to bottom. With $\phi = 0.4$, the effective refractive index of the nanowires is $n_{\text{EMT}} = 1.55$, close to the refractive index of the dielectric, $n_{\text{BaF}_2} = 1.44$

198 at 30° C and 8 µm wavelength. As the nanowire width becomes infinitesimally small the FOM 199 plateaus close to 1.5. This makes sense as the VO2 layer seeks to obtain a refractive index close to 200 unity. The spectra calculated with an 80 nm-thick effective nanowire medium resulted the same 201 normal emissivity, with discernable differences of off-normal spectra due to the anisotropic effective medium distribution [34]. The refractive index of the sub-monolayer VO₂ is $n_{\text{VO}_2} = 2.38$, 203 which is a gradual transition to higher index before the reflecting and opaque silver substrate. The 204 power is concentrated in a sliver at the interface between the VO₂ sub-monolayer and silver. Using 205 the penetration depth definition $\delta = \lambda / 4\pi \kappa$, the attenuation depth in the silver substrate is 11 nm, 206 almost negligible. Some absorption is seen in $VO₂$, and none through the BaF₂ dielectric cavity 207 layer, as the fields are transmitted in the cold state. Since the extinction coefficient of $\rm VO_2$ is non-208 zero (κ = 0.08 at 8 μ m) in the transparency region shown in Fig. 2(a), the reflection is not perfect. 209 This 5.7% VO2 monolayer thickness to its penetration depth ratio is expressed correspondingly in 210 the minimum emissivity at 8μ m shown in Fig. 3(a).

211 On the other hand, from Fig. 5 (b), the electromagnetic field power dissipation density (PDD) 212 within the VO2 nanowire and VO2 bottom layer at the hot state temperature shows higher 213 absorption compared to lower temperature due to its much higher *κ* value of 3.3. In the hot state, 214 the 450 nm-thick VO2 sub-monolayer becomes to the metallic substrate, such that the lossless 215 dielectric insulator becomes a Fabry-Perot resonator. This plasmonic resonance is induced within 216 the nanowire and within the BaF2 layer due to its metallic phase in vanadium dioxide layer, 217 behaving like metal-insulator-metal (MIM) [40]. Localization of power absorption can be up to 218 1000 W/m^3 in both VO₂ layers. The finesse in this optimized design is due to the upper metal layer 219 being a loosely-packed thin metal film, such that enough radiation is able to enter the dielectric 220 cavity and constructively interfere to induce maximum absorption. Hence, the adaptive design 221 switches from anti-reflecting coating by refractive index gradient layering to a plasmonic resonant 222 cavity that concentrates power absorption/emission within the VO₂ during the coating's hot state.

223 Although many optical materials and coatings should perform well regardless of radiation 224 incident angle, some angular dependence is observed at far infrared region at around 28 μm. In 225 Figure 6, we investigate the anomalous high absorption marked by the TM wave "lobes" in Fig. 4 226 (a) and (b). The absorptive effect is due to a thick $BaF₂$ layer, where spectral emissivity increases 227 with incident angle and reaches up to 1.0 at higher angles due to increasing value of *κ* value and 228 propagation length. Neither the silver substrate nor the VO2 components have effects on the 229 oblique angle emissivity. The incident far infrared light is trapped in the slightly lossy cavity and 230 constructs multiple reflections between $VO₂ NW$ and $VO₂ sublayer$. This phenomenon is only 231 observed in TM waves at oblique incident angles, as the electric fields form surface plasmon modes 232 at the lower corners of the dielectric VO2 nanowires [41] The emissivity is further enhanced at hot 233 state (Figs. 6 d-f) because metallic phase in VO2 absorbs the light, especially the under-cavity 234 monolayer. At steeper angles, emissive power is then concentrated within BaF2 cavity, as the 235 mechanism transitions toward cavity extinction and trapping. In practice, this angle-dependent 236 emissivity in cold state should be avoided to improve its overall performance with radiation 237 coming from any polarization type. With this consideration of the Reststrahlen band extinction of 238 this particular infrared material, other dielectric materials should be considered as replacement, as 239 discussed in the next section.

240 *3.2. Performance Enhancement by Dielectric Spacer Types*

241 Figure 7 (a) shows a sweeping of a correspondingly quarter-wave thick layer of purely real 242 component and wavelength-independent refractive indices from unity to Germanium $(n = 4.0)$. 243 The VO2 parameters are unchanged from the previously-found optimized configuration. Here, a 244 higher FOM performance was found by an idealized dielectric spacer of refractive index *n* = 2.2. 245 This FOM can be as high as 1.86, slightly higher compared to the optimized structure with BaF2 246 of 1.47. In this regard, we learn that other broadly infrared-transparent materials with higher index 247 such as silicon $(n = 3.4)$ could achieve similar turn-down performance. Other low-index materials 248 can have similar FOM as the BaF₂ configuration, such as potassium chloride ($n = 1.49$) and 249 potassium bromide ($n = 1.55$), as long as the Reststrahlen band is far beyond the thermal infrared 250 regime (λ > 40 µm). Ideally, medium-index materials such as zinc selenide ($n = 2.4$) or zinc sulfide 251 ($n = 2.2$) can deliver FOM > 1.47 . It becomes pressing to seek crystalline and interfacial 252 compatibility between these medium-index dielectrics with VO2. Difficulties may arise in more 253 common dielectric oxides with medium-index, such as silicon dioxide or titanium dioxide, due to 254 their Lorentz absorption in the mid- to far-infrared [42].

255 In the next investigation shown in Fig. 7 (b), it was found the filling ratio of the VO2 NW array 256 plays an important role in high reflectance in cold state due to index-matching between the $VO₂$ 257 NW / air effective medium (EMT) layer and the dielectric material. The previous investigation for 258 BaF₂ shows it reached a maximum at $\phi = 0.4$, but it is not true for the other dielectric materials. 259 The highest FOM is achieved for both ZnS and the constant $n = 2.2$ index at $\phi = 0.3$. The slightly 260 lower FOM of ZnS compared to constant *n* = 2.2 is due to its closer Reststrahlen band peak at 30.5 261 um [37]. For a high-index dielectric such as Si, the best filling ratio of the VO₂ NW array is zero, 262 which is unrealistic. This is due to the departure of index-gradient matching. For instance, the 263 effective refractive index within the visible to near infrared region of EMT is $n_{\text{EMT}} = 1.0 \approx 2.0$ for 264 filling ratio of $\phi = 0.4$, which matches overall with the refractive index of the BaF₂ cavity, $n_{\text{BaF2}} =$ 265 1.4~1.5. Other dielectric materials such as zinc sulfide (ZnS) and silicon (Si) may replace BaF₂ 266 with an appropriate filling ratio to improve overall reflectance, but with consideration of realizable 267 nanowire sizing. Other dielectric spacers have been used in other studies of turn-down coatings, 268 which we will make a comparison.

269 *3.3 Comparison of Radiative Turn-Down Performance*

270 Figures 8 (a) and (b) compares the reflectance at cold state and the emissivity at the hot state 271 of our optimized structure (VO₂ nanowires / BaF₂ / VO₂) with a rudimentary quarter-wave (QW) 272 layers as first-order approximation (BaF₂ QW / VO₂ QW), a Fabry-Perot resonator (thin VO₂ / Si) 273 [9], and a multi-component radiative cooler system (Multilayer band-pass filter / $VO₂$ / MgF₂) 274 [15]. The QW layers are presented to demonstrate its comparable high coating transmissivity as a 275 proof of an anti-reflecting film, similar to our optimized nanowire structure in the cold state. The 276 Planck emissive power spectrum at 80° C is also posed to predict the total emissivity between the 277 different configurations. Table I compares the summative radiative performances. The FOM of the 278 optimized structure is 1.47, higher than other realized structures of 0.86 and 0.6, respectively. The 279 basic quarter-wave layers that share the same material composition as our optimized structure has 280 a higher FOM of 1.06. The absence of the semi-metallic upper nanowire array layer produces no 281 cavity mode interference, but shares a peak local emissivity near 8 µm. The key understanding is 282 the absence of the upper solid VO₂ layer for the purpose of creating a Fabry-Perot cavity in turn 283 reduces performance, especially the needed high reflectance in the cold state.

284 Thus, the VO2 nanowire array is a good compromise in gaining the high turn-down, while any 285 Fabry-Perot multilayer configuration has lower turn-down performance due to narrower band 286 emission. We noticed some consequential differences in performance in the multi-component 287 Fabry-Perot cooler system from our recalculations is likely due to absorption by MgF2 near its

288 Reststrahlen band near 20 μ m [38], as well as differences from more modern spectroscopic surveys 289 of VO2 thin films [35, 43]. Additionally, Table 1 compares the quantities of radiative heat emitted 290 to the surroundings. The emitted power at normal incidence is given by,

$$
E_{\rm emit} = \int_{0.3\,\mu\rm m}^{30\,\mu\rm m} \varepsilon_{\lambda,T} E_{\rm BB,T} d\lambda \tag{7}
$$

292 where this quantity represents the potential to emit to a neighboring reradiating surface, such as a 293 multilayer insulation blanket [44]. The error to these figures is no more than 10% due to the upper 294 wavelength cutoff at room temperature and above. We also calculate the integrated hemispherical 295 emissivity combined with absorption from atmospheric radiation, given by,

296
$$
q''_{\text{net}} = \int_{0.3\mu\text{m}}^{30\mu\text{m}} \varepsilon_{\lambda,T}^{\text{h}} E_{\text{b},T} d\lambda - \int_{0.3\mu\text{m}}^{30\mu\text{m}} (1 - \tau_{\text{atm},\lambda}) \varepsilon_{\lambda,T}^{\text{h}} E_{\text{BB},T_{\text{amb}}} d\lambda \tag{8}
$$

297 where *τ*atm,*λ* is the atmospheric transparency shown in Fig. 2(b) [45]. The ambient temperature *T*amb 298 is assumed to be 290 K. The purpose of presenting this combined net radiative flux is to assess the 299 respective coatings' performance exposed to diffuse cloudy or night sky. By analyzing Eq. (7), our 300 optimized structure produces 560 W/m² in the hot state, while just 53 W/m² in the cold state. This 301 ratio of power turn-down is 10.6:1. An even higher turn-down ratio is seen with Eq. (8), for net 302 hemispherical heat flux with atmosphere, where the ratio is 14.7:1. The magnitudes of the hot state 303 emissive power is not insignificant compared to the irradiative power flux from the Sun (~1400) $304 \,$ W/m²). The net radiative performance of comparable structures also show good turn-down but at 305 predicted lower hot state magnitudes.

306 Although the emissive power turn-down ratio for the simpler QW layers is higher (14.3:1), the 307 maximum emitted power is lower, therefore the reduced FOM. This FOM accounts for both the 308 turn-down ratio as well as the emissive power difference between hot and cold state. A higher 309 magnitude emissive power at the hot state is therefore more important, especially for compact 310 components with small radiating surface areas. The optimized VO₂ NW design can also provide 311 dense thermal radiative energy directed toward the atmosphere, almost doubling the capability for 312 radiative rejection compared to other designs. Furthermore, we learn that the basic quarter-wave 313 structure in fact outperforms a Fabry-Perot solid VO2 layer on dielectric. This means the concept 314 of a Fabry-Perot structure may not be best suited, compared to a simpler dual anti-reflection layer. 315 We note the performance is bolstered by absorption within the dielectric medium at off-normal 316 incident angles. At these emissive power magnitudes at high temperature, these coatings may be 317 capable of passive radiative cooling under the Sun via careful tuning of spectral response in the 318 visible wavelength.

319 *3.4. Evaluation of Daytime Radiative Cooling*

320 This section assesses the possibility of the optimized coating as a daytime radiative cooler, and 321 the metrics developed to quantify this capability. The Daytime Cooling Merit (DCM) is defined in 322 Eq. (9),

323
$$
DCM = \frac{P_{\text{cool,350}}}{P_{\text{cool,300}}} = \frac{P_{\text{cot},350} - P_{\text{atm,350}} - P_{\text{sun,350}} + P_{\text{con,350}}}{P_{\text{cot},300} - P_{\text{atm,300}} - P_{\text{sun,300}} + P_{\text{con,300}}}
$$
(9)

324 as a ratio of energy balances from the diffuse coating (coat), atmosphere (atm), the Sun (sun), and 325 combined conduction and convective cooling (con) to an ambient temperature in atmosphere *T*amb $326 = 290$ K. The coating radiative power flux in W/m² is obtained by hemispherical integration of the 327 spectral directional emissivity with blackbody temperature function of the coating. The incoming 328 atmospheric power flux is calculated with the diffuse atmospheric transparency spectrum seen in 329 Fig. 3(a), and integrated with the spectral directional absorptivity at ambient temperature. We 330 obtained the solar absorption spectrum from $I_{AM1.5, \lambda}$ at normal incidence spectral absorptivity, as 331 the coating can be mechanically dialed to be sun-pointing. Lastly, heat rejection due to both 332 convection and conduction to ambient is appropriately grouped into an overall coefficient *h*c, 333 which is conservatively set as 10 W/m²·K. The combined power from this component is $P_{\text{con,T}} =$ 334 *h*_c $(T - T_{amb})$. We note that the integration cutoff for solar irradiation at the lower wavelength of 335 0.3 μm gives 3% error, compared to the 9% error for the 30 μm upper limit in bodies at terrestrial 336 temperatures.

337 Applying Eq. (9) onto the optimized structure results in DCM = $P_{\text{cool,350}}$ / $P_{\text{cool,300}} = 271$ / (- 338 615) = -0.44. This negative DCM indicates that the coating absorbs more sunlight rather than emit 339 heat at the low temperature near ambient. However, at the high temperature which VO2 becomes 340 metallic, the coating rejects more heat than it absorbs. Since its absorptivity in the visible to near 341 infrared region is high for any temperature as shown in Fig. 3, the coating's outgoing emissive 342 power, *P*coat,*T* must overcome the sunlight absorption power, *P*sun*,T*. In Figure 9, plotting the total 343 radiative outgoing power with temperatures from ambient to 370 K, an equilibrium temperature is 344 reached at around $T = 345$ K ($P_{\text{cool},T} = 0$) which is just above the phase transition temperature of

345 vanadium dioxide at 340 K. The radiative cooling power drastically increases after passing the 346 VO₂ phase transition temperature, and it can attain powers up to 470 W/m². This is similar to the 347 net radiative cooling power at hot state in Table 1. The performance somewhat leans on the 348 contribution of combined convection and conduction cooling power, in which a well-insulated 349 environment around the coating may mean less cooling capability at the hot state. Therefore, the 350 coating is able to reach self-equilibrium near the phase transition temperature of VO2. In the 351 insulating phase near ambient temperature, the coating warms up, but in the metallic phase at high 352 temperatures, it passively cools.

353 This cooling capability only in the hot state exceeds that of previously designed daytime 354 radiative cooling coatings, such as $SiO₂$ / HfO₂ multilayer [46], $SiO₂$ -polymer hybrid metamaterial 355 [47], and plain PDMS coatings [48]. Table 2 shows that daytime equilibrium temperature of the 356 optimized grating is greater than ambient temperature, which does not compare with plain daytime 357 radiative cooler materials and designs. Rather, the high cooling power just beyond the $VO₂$ 358 transition temperature is noticeably significant compared to others. Therefore, we learn that the 359 optimized VO₂ NW / BaF₂ / VO₂ is useful as a radiative cooler only when in shade and not placed 360 under the sun. However, it is commendable for this 2 μ m-thin coating to ensure that an equilibrium 361 temperature can be obtained close to 345 K. This is not only helpful in maintaining efficiency in 362 photovoltaic devices, but also it can be used for thermal management of components such as 363 rechargeable batteries, fuel tanks, and engines on both terrestrial and space vehicles.

364 **4. CONCLUSION**

365 We have proposed a self-adaptive high turn-down VO_2 nanowire / BaF₂ / VO_2 / silver thin film 366 of around 2 μ m for passive thermal management applications. Our Monte-Carlo optimization 367 method was utilized to obtain the optimal structure parameters for $\rm VO_2$ components. It is compared 368 with Fabry-Perot multilayers using VO2, and a higher figure of merit (FOM) of 1.47 is obtained 369 compared to other structures (FOM \leq 1). Ideally, the optimal refractive index of the dielectric 370 spacer is $n = 2.2$, which is slightly higher than $BaF_2(n = 1.55)$. The electric field is reflected at the 371 interface between VO2 bottom layer and silver for lower temperature for high reflectance, but a 372 high value of power dissipation density (PDD) is observed within the VO₂ in higher temperature, 373 leading to high emissivity in infrared region. The optimized structure provides cooling power of 271 W/m² at 350 K whose power is higher compared to previously studies structures. Lastly, this 375 work provides the idea of computational method for optimizing the photonic structures to obtain 376 the desired optical properties. The obtained data may be utilized for machine learning (ML) 377 technique to obtain predictive FOM with complex structural geometries and exotic materials, both 378 dielectrics and phase transition. This structure can be extended to two-dimensional gratings to 379 possibly further improve its figure-of-merit (FOM) as well as daytime radiative cooling merit 380 (DCM) turn-down to an even higher value. This turn-down allows the device to self-reject the heat 381 out of the devices such as solar cells, computer systems, engines, and functions as self-adaptive 382 radiative cooling device.

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Fig. 1. (a) Illustration and schematic of Vanadium Dioxide (VO₂) nanowire / Dielectric material / VO2 sub-monolayer coating on Silver (Ag) substrate. (b) Nomenclature of geometric parameters of the coating: Dielectric cavity or monolayer thicknesses d , nanowire grating period Λ , its width *w*, height *h*, and groove spacing *b*.

Fig. 2. (a) Refractive index of vanadium dioxide (VO₂) at $T = 30^{\circ}$ C and $T = 80^{\circ}$ C obtained from Ref. [35]. The highlighted region shows near-zero extinction coefficient of the refractive index (k) at the cold state. (b) Comparison of refractive index of dielectric materials, including barium fluoride (BaF2), magnesium fluoride (MgF2), silicon (Si), and zinc sulfide (ZnS).

Fig. 3. (a) The averaged emissivity spectrum calculated with Rigorous Coupled-Wave Analysis (RCWA). The dashed lines show the hemispherical emissivity spectra. The background atmospheric transparency spectrum is shown in Ref. [45]. (b) Normal emissivity spectrum calculated with Effective Medium Theory (EMT) of optimized VO2 Nanowire / BaF2 / VO2 coating on Ag substrate for TM (solid line) and TE wave (dashed line).

Fig. 4. Spectral and incident angle-dependent emissivity contours of TM wave at (a) cold and (b) hot states, and TE wave at (c) cold and (d) hot states, calculated by RCWA.

Fig. 5. Power dissipation density (PDD) distribution (TM wave only) of the optimized VO₂ NW / BaF₂ / VO₂ design for (a) cold state ($T = 30^{\circ}$ C) and (b) hot state ($T = 80^{\circ}$ C) calculated by RCWA. The white dashed box shows the inset figures within the VO2 nanowire array region. The pink lines delineate the interfaces in the structure.

Fig. 6. Oblique TM wave power dissipation density (PDD) distribution of the optimized VO₂ NW / BaF2 / VO2 design at λ = 28 μm for incident angles: (a) *θ* = 0°, (b) *θ* = 30°, and (c) *θ* = 60° at cold state, and (d) $\theta = 0^{\circ}$, (e) $\theta = 30^{\circ}$, and (f) $\theta = 60^{\circ}$ at hot state calculated by RCWA.

Fig. 7. (a) Relationship of FOM and the refractive index of the quarter-wave thick spacer. (b) The correlation of FOM and filling ratio of VO2 nanowires with different dielectric materials including BaF2 (black), ZnS (red), Si (blue), and constant *n* = 2.2 (green).

Fig. 8. Comparison of (a) normal reflectivity and (b) normal emissivity spectra of this optimized grating (VO₂ Nanowires / BaF₂ / VO₂), simple quarter-wave layers (BaF₂ QW / VO₂ QW), a Fabry-Perot resonator (VO₂ / Si), and a radiative cooler system (Band-pass filter / VO₂ / MgF₂). All are opaque coatings on metal substrates. The Planck blackbody emissive power function (*E*b) at 80°C is plotted in shaded gray.

Table 1. Comparison of performances among similar turn-down coatings, showing the FOM defined in Eq. (3), the emitted radiation flux (W/m^2) from the coating (E_{emit}), and the net radiative heat flux between the coating and atmosphere at 290 K (q''_{net}).

Structure	FOM	$E_{\rm emit}$		$q''_{\rm net}$	
		30° C	80° C	30° C	80° C
Optimized Grating (VO ₂ Nanowires / BaF ₂ / VO ₂)	1.47	53	560	27	396
Quarter-Wave Layers ($BaF2 QW / VO2 QW$)	1.06	31	443	20	330
Fabry-Perot Resonator (VO_2/Si)	0.86	34	359	18	265
Radiative Cooler System (Filter / $VO2$ / MgF ₂)	0.60	61	202	17	144

Fig. 9. Overall coating radiative cooling power, P_{cool} and the temperature of the coating (blue line). The red, light blue, orange, and green solid lines represent P_{coat} , P_{atm} , P_{sun} , and P_{con} , respectively. The shaded area represents the metallic phase of VO2.

Table 2. Comparison of temperature difference $T_{\text{coating}} - T_{\text{amb}}$ (K), maximum cooling power $(W/m²)$, and the Daytime Cooling Merit defined in Eq. (9), with other daytime radiative cooling coatings.

Structure	$T_{\text{coating}}-T_{\text{amb}}(K)$	Cooling power (W/m^2)	DCM
Optimized Grating	$+46$	271 (350 K)	-0.44
$SiO2/HfO2 Multilayer$	-4.9	82	1.86
Glass-Polymer Hybrid Metamaterial		>110	
PDMS $(300 \mu m)$	-6	188	1.86